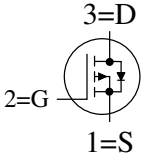
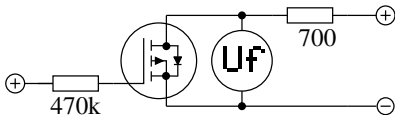


IRF5305



P-E-MOS 123=SGDM
1-4-3 $U_f = 603\text{mV}$



P-E-MOS 123=SGDM
 $C = 2.22\text{nF}$ $U_t = 3.6\text{V}$

